

## **isc** Silicon PNP Darlington Power Transistor

# **BD678**

### DESCRIPTION

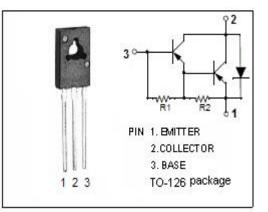
Collector–Emitter Breakdown Voltage—

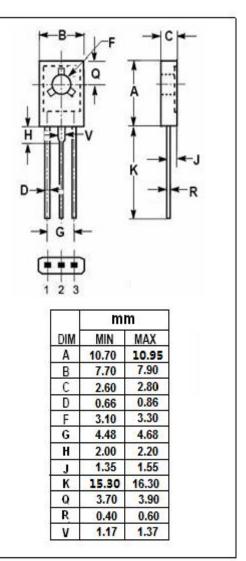
: V<sub>(BR)CEO</sub> = -60

- DC Current Gain—
- : h<sub>FE</sub> = 750(Min) @ I<sub>C</sub>= -1.5 A
- Complement to Type BD677
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **APPLICATIONS**

• Designed for use as output devices in complementary general-purpose amplifier applications.





### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| PARAMETER                                | VALUE                                                                                                                                                                                              | UNIT                                                                                                                                                                                                   |  |  |  |  |  |
|------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|--|--|--|--|
| Collector-Base Voltage                   | -60                                                                                                                                                                                                | V                                                                                                                                                                                                      |  |  |  |  |  |
| Collector-Emitter Voltage                | -60                                                                                                                                                                                                | V                                                                                                                                                                                                      |  |  |  |  |  |
| Emitter-Base Voltage                     | -5                                                                                                                                                                                                 | V                                                                                                                                                                                                      |  |  |  |  |  |
| Collector Current-Continuous             | -4                                                                                                                                                                                                 | А                                                                                                                                                                                                      |  |  |  |  |  |
| Base Current                             | -0.1                                                                                                                                                                                               | А                                                                                                                                                                                                      |  |  |  |  |  |
| Collector Power Dissipation $T_c$ =25 °C | 40                                                                                                                                                                                                 | W                                                                                                                                                                                                      |  |  |  |  |  |
| Junction Temperature 150                 |                                                                                                                                                                                                    | °C                                                                                                                                                                                                     |  |  |  |  |  |
| Storage Temperature Range                | -55~150                                                                                                                                                                                            | °C                                                                                                                                                                                                     |  |  |  |  |  |
|                                          | PARAMETER   Collector-Base Voltage   Collector-Emitter Voltage   Emitter-Base Voltage   Collector Current-Continuous   Base Current   Collector Power Dissipation   Tc=25°C   Junction Temperature | PARAMETERVALUECollector-Base Voltage-60Collector-Emitter Voltage-60Emitter-Base Voltage-5Collector Current-Continuous-4Base Current-0.1Collector Power Dissipation<br>Tc=25°C40Junction Temperature150 |  |  |  |  |  |

#### THERMAL CHARACTERISTICS

| SYMBOL              | PARAMETER                            |      | UNIT |
|---------------------|--------------------------------------|------|------|
| R <sub>th j-c</sub> | Thermal Resistance, Junction to Case | 3.13 | °C/W |



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### **ELECTRICAL CHARACTERISTICS**

#### 

| SYMBOL               | PARAMETER                            | CONDITIONS                                                                                                     | MIN | MAX          | UNIT |
|----------------------|--------------------------------------|----------------------------------------------------------------------------------------------------------------|-----|--------------|------|
| V <sub>(BR)CEO</sub> | Collector-Emitter Breakdown Voltage  | I <sub>C</sub> = -50mA; I <sub>B</sub> = 0                                                                     | -60 |              | V    |
| V <sub>CE(sat)</sub> | Collector-Emitter Saturation Voltage | I <sub>C</sub> = -1.5A; I <sub>B</sub> = -30mA                                                                 |     | -2.5         | V    |
| V <sub>BE</sub> (on) | Base-Emitter On Voltage              | I <sub>C</sub> = -1.5A; V <sub>CE</sub> = -3V                                                                  |     | -2.5         | V    |
| I <sub>CEO</sub>     | Collector Cutoff Current             | V <sub>CE</sub> = -60V; I <sub>B</sub> = 0                                                                     |     | -0.5         | mA   |
| Ісво                 | Collector Cutoff Current             | V <sub>CB</sub> = -60V; I <sub>E</sub> = 0<br>V <sub>CB</sub> = -60V; I <sub>E</sub> = 0;T <sub>C</sub> = 100℃ |     | -0.2<br>-2.0 | mA   |
| I <sub>EBO</sub>     | Emitter Cutoff Current               | V <sub>EB</sub> = -5V; I <sub>C</sub> = 0                                                                      |     | -2.0         | mA   |
| hfe                  | DC Current Gain                      | Ic= -1.5 A ; V <sub>CE</sub> = -3V                                                                             | 750 |              |      |

### **NOTICE:**

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